TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC4020AP,TC74HC4020AF,TC74HC4020AFN TC74HC4040AP,TC74HC4040AF,TC74HC4040AFN

TC74HC4020AP/AF/AFN 14-Stage Binary Counter TC74HC4040AP/AF/AFN 12-Stage Binary

Counter

The TC74HC4020A/TC74HC4040A are high speed CMOS BINARY COUNTER/DIVIDERs fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS dissipation.

The TC74HC4020A is a 14-STAGE BINARY COUNTER, and the TC74HC4040A is a 12-STAGE BINARY COUNTER.

Setting CLR to high resets the counter to low.

A negative transition on the CK input brings one increment into the counter.

The TC74HC4020A provides 12 divided outputs: 1'st stage and stage 4 thru stage 14. At Q14, a 1/16384 divided frequency will be output.

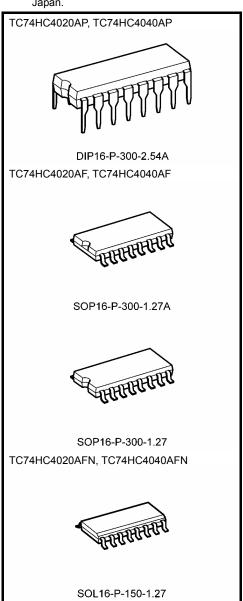
The TC74HC4040A provides all divided output stages, and at Q12, a 1/4096 divided frequency will be output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $f_{max} = 73 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~6 V
- Pin and function compatible with 4020B/4040B

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

 DIP16-P-300-2.54A
 : 1.00 g (typ.)

 SOP16-P-300-1.27A
 : 0.18 g (typ.)

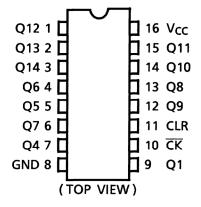
 SOP16-P-300-1.27
 : 0.18 g (typ.)

 SOL16-P-150-1.27
 : 0.13 g (typ.)

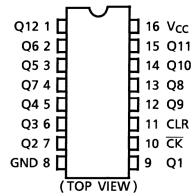


Pin Assignment

TC74HC4020A

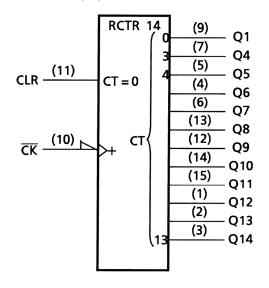


TC74HC4040A

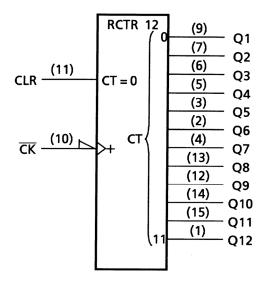


IEC Logic Symbol

TC74HC4020A



TC74HC4040A



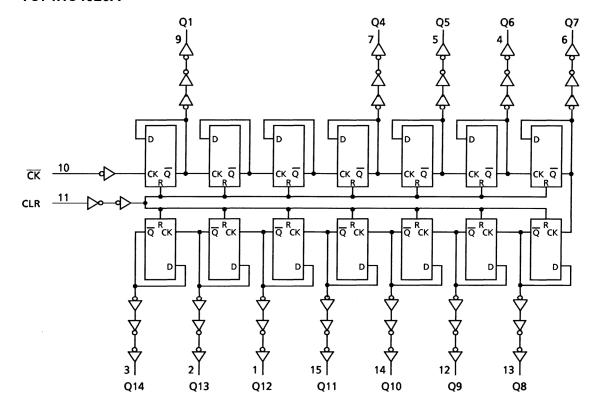
Truth Table

СК	CLR	Output State
Х	Н	All Output = "L"
	L	No Change
\Box	L	Adovance to Next State

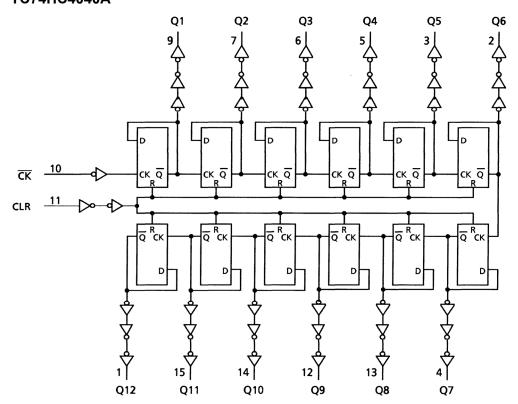
X: Don't care

System Diagram

TC74HC4020A



TC74HC4040A





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	٧
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of Ta = -40 to $65^{\circ}C$. From Ta = 65 to $85^{\circ}C$ a derating factor of -10 mW/°C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		0~1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0~500 (V _{CC} = 4.5 V)	ns
		0~400 (V _{CC} = 6.0 V)	

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

0			Test Condition		Ta = 25°C			Ta = -40~85°C		11.26
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
				2.0	1.50	_	_	1.50	_	
High-level input voltage	V _{IH}		_	4.5	3.15	_	_	3.15	_	V
				6.0	4.20		_	4.20	_	
				2.0	_	_	0.50	_	0.50	
Low-level input voltage	V _{IL}		_	4.5	_	_	1.35	_	1.35	V
				6.0	_	_	1.80	_	1.80	
	V _{ОН}	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
			I _{OH} = -20 μA	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0	_	5.9	_	V
Ü			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
	V _{OL}	V _{IN} = V _{IH} or		2.0	_	0.0	0.1	_	0.1	
			$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
		V _{IL}	I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33	
			I _{OL} = 5.2 mA	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	_	_	±0.1	_	±1.0	μА
Quiescent supply current	Icc	$V_{IN} = V_C$	_C or GND	6.0	_	_	4.0	_	40.0	μА

Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Test Condition			Ta = −40 ~85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	*		2.0	_	75	95	
(CK)	t _{W (L)}	_	4.5	_	15	19	ns
(CK)	t _{W (H)}		6.0	_	13	16	
Minimum pulse width			2.0	_	75	95	
(CLR)	t _{W (H)}	_	4.5	_	15	19	ns
(CLK)			6.0	_	13	16	
	t _{rem}	_	2.0	_	25	30	
Minimum removal time			4.5	_	5	6	ns
			6.0	_	5	5	
	f	_	2.0	_	6	5	
Clock frequency			4.5	_	30	24	MHz
			6.0	_	35	28	



AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C, input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{TLH} t _{THL}	_	_	4	8	ns
Propagation delay time (CK -Q1)	t _{pLH}	_	_	16	24	ns
Propagation delay time (Qn-Qn + 1)	$\Delta t_{\sf pd}$	_	_	5	14	ns
Propagation delay time (CLR)	t _{pHL}	_	_	14	24	ns
Maximum clock frequency	f _{max}	_	33	73	_	MHz

AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

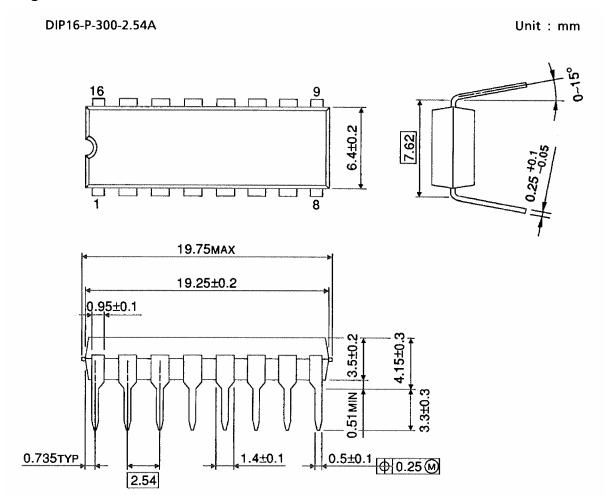
		Test Condition		-	Га = 25°C	;	Ta = -4			
Characteristics Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit		
	4		2.0	_	30	75	_	95		
Output transition time	t _{TLH}	_	4.5	_	8	15	_	19	ns	
	t _{THL}		6.0	_	7	13	_	16		
Propagation delay	4		2.0	_	70	145	_	180		
time	t _{pLH}	_	4.5	_	20	29	_	36	ns	
(CK -Q1)	t_{pHL}		6.0	_	17	25	_	31		
Propagation delay			2.0	_	20	75	_	95		
time	$\Delta t_{\sf pd}$	_	4.5	_	6	15	_	19	ns	
(Qn-Q + 1)	·			6.0	_	4	13	_	16	
Propagation delay			2.0	_	55	140	_	175		
time	t _{pHL}	_	4.5	_	17	28	_	35	ns	
(CLR)			6.0		14	24	_	30		
			2.0	6	17	_	5	_		
Maximum clock frequency	f _{max}	_	4.5	30	66	_	24	_	MHz	
requeriey			6.0	35	78	_	28	_		
Input capacitance	C _{IN}	_	•	_	5	10	_	10	pF	
Power dissipation	C _{PD}	TC74HC4020A			27	_	_	_	nE	
capacitance	(Note)	TC74HC4040A		_	37		_		pF	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

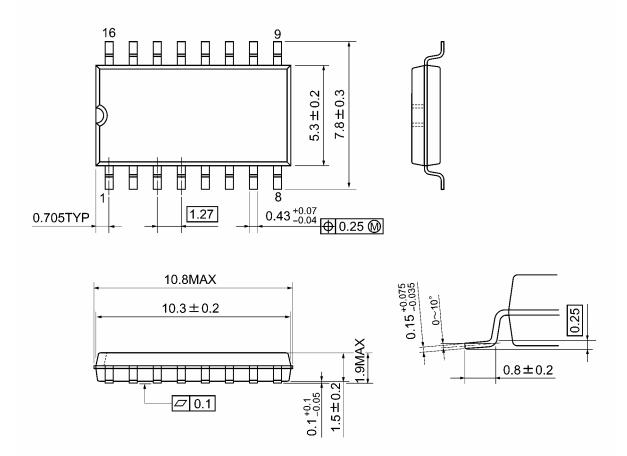
Package Dimensions



Weight: 1.00 g (typ.)

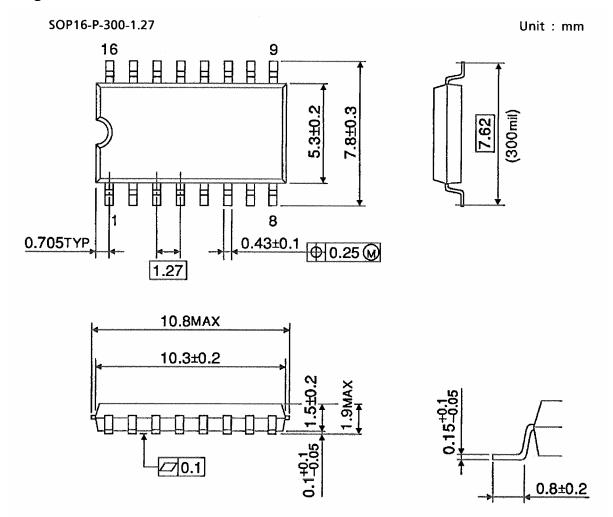
Package Dimensions

SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

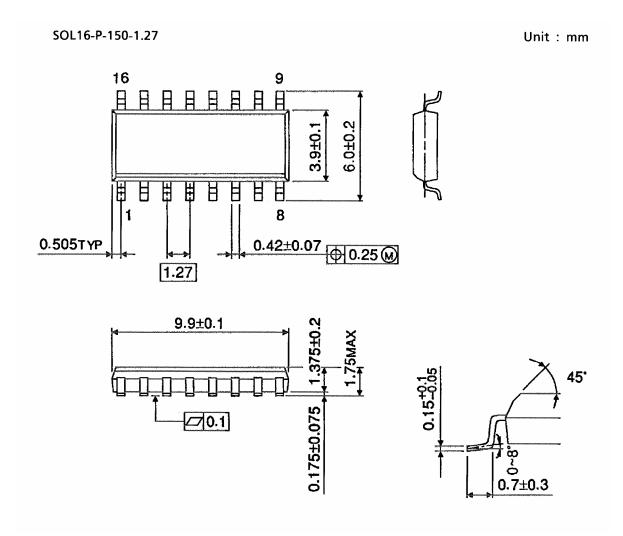
Package Dimensions



Weight: 0.18 g (typ.)



Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

Note: Lead (Pb)-Free Packages

DIP16-P-300-2.54A SOP16-P-300-1.27A SOL16-P-150-1.27

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